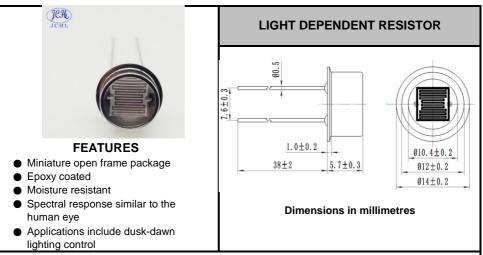


晶创和立科技 GL12530F MINIATURE CADMIUM SULPHIDE PHOTOCONDUCTIVE CELL



SPECIFICATION AND PERFORMANCE

Model	Vmax (VDC)	Pmax (mW)	Ambient temp(℃)	neak	Light Resistance at 10Lux (KΩ)	Dark Resistance (MΩ)	Gamm a value at 100- 10Lux	Response Lime (ms)	
								Rise Time	Decay time
GL12530F	200	400	-30~+70	540	45-100	5	0.85	30	30

Measuring Conditions

KΩ **Spectral Response** 1. Light resistance: 1000 Measured at 10 Lux with standard light A (2854K color temperature) and 2hr Relative Sensitivity (%) illumination at 400-600 lux prior to testing. 100 2. Dark Resistance: Measured 10 senconds after closed 10 lux. 100 80 3. Gamma Characteristic: Between 10 lux ande 100 lux and given by 60 $\gamma = Ig(R10/R100)$ R10、R100 Cell resistance at 10 lux and 40 100 lux. 10 The error of γ is ± 0.1 . 20 4. Pmax: Max. power dissipation at ambient temperature of 25 °C. 0 400 500 600 700 800 900 1000 1 5. Vmax: 10 100lux 1 Max. voltage in darkness that may be Wavelength (nm) applied to the cell continuously.

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